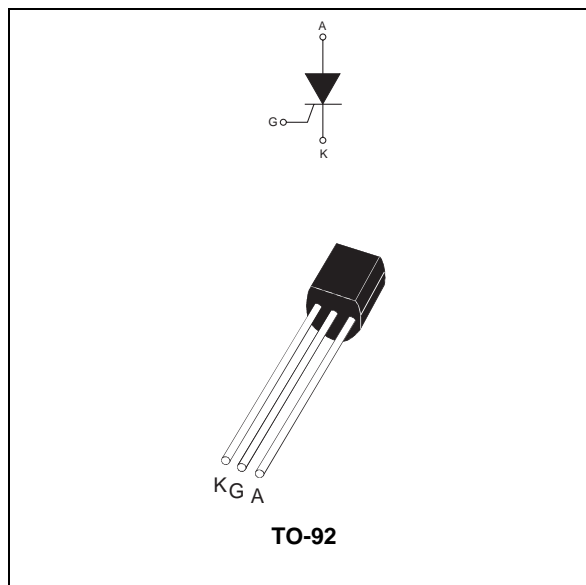


MAIN FEATURES:

Symbol	Value	Unit
$I_{T(RMS)}$	0.8	A
V_{DRM}/V_{RRM}	600	V
I_{GT}	200	μA

DESCRIPTION

Thanks to highly sensitive triggering levels, the X006 SCR series is suitable for all applications where the available gate current is limited, such as ground fault circuit interrupters, overvoltage crowbar protection in low power supplies, capacitive ignition circuits, ...



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state current (180° conduction angle)		$T_I = 85^\circ C$ 0.8	A
$I_{T(AV)}$	Average on-state current (180° conduction angle)		$T_I = 85^\circ C$ 0.5	A
I_{TSM}	Non repetitive surge peak on-state current	$t_p = 8.3 \text{ ms}$	$T_j = 25^\circ C$ 10	A
		$t_p = 10 \text{ ms}$		
I^2t	I^2t Value for fusing	$t_p = 10 \text{ ms}$	$T_j = 25^\circ C$ 0.25	A^2S
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100 \text{ ns}$	$F = 60 \text{ Hz}$	$T_j = 125^\circ C$ 50	$A/\mu s$
I_{GM}	Peak gate current	$t_p = 20 \mu s$	$T_j = 125^\circ C$ 1	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125^\circ C$ 0.1	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range		- 40 to + 125 - 40 to + 125	$^\circ C$

X00602MA

ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise specified)

Symbol	Test Conditions		X00602MA	Unit
I _{GT}	V _D = 12 V R _L = 140 Ω	MIN.	15	μA
		MAX.	200	μA
V _{GT}		MAX.	0.8	V
V _{GD}	V _D = V _{DRM} R _L = 3.3 kΩ R _{GK} = 1 kΩ T _j = 125°C	MIN.	0.2	V
V _{RG}	I _{RG} = 10 μA	MIN.	5	V
I _H	I _T = 50 mA R _{GK} = 1 kΩ	MAX.	5	mA
I _L	I _G = 1 mA R _{GK} = 1 kΩ	MAX.	6	mA
dV/dt	V _D = 67 % V _{DRM} R _{GK} = 1 kΩ T _j = 125°C	MIN.	25	V/μs
V _{TM}	I _{TM} = 1 A t _p = 380 μs T _j = 25°C	MAX.	1.35	V
V _{th0}	Threshold voltage T _j = 125°C	MAX.	0.85	V
R _d	Dynamic resistance T _j = 125°C	MAX.	245	mΩ
I _{DRM} I _{RRM}	V _{DRM} = V _{RRM} R _{GK} = 1 kΩ	T _j = 25°C	MAX.	μA
		T _j = 125°C		
			1	
			100	

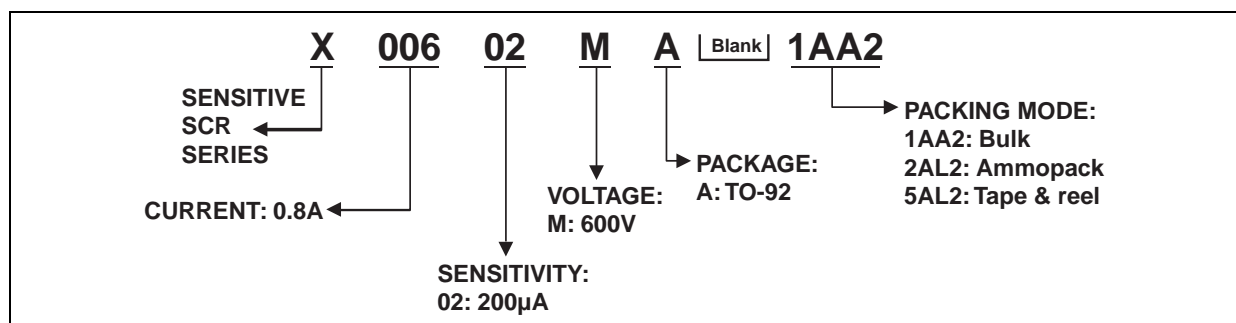
THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th(j-l)}	Junction to lead (DC)	70	°C/W
R _{th(j-a)}	Junction to ambient (DC)	150	°C/W

PRODUCT SELECTOR

Part Number	Voltage	Sensitivity	Package
X00602MA	600 V	200 μA	TO-92

ORDERING INFORMATION



OTHER INFORMATION

Part Number	Marking	Weight	Base Quantity	Packing mode
X00602MA 1AA2	X0602MA	0.2 g	2500	Bulk
X00602MA 2AL2	X0602MA	0.2 g	2000	Ammopack
X00602MA 5AL2	X0602MA	0.2 g	2000	Tape & reel

Fig. 1: Maximum average power dissipation versus average on-state current.

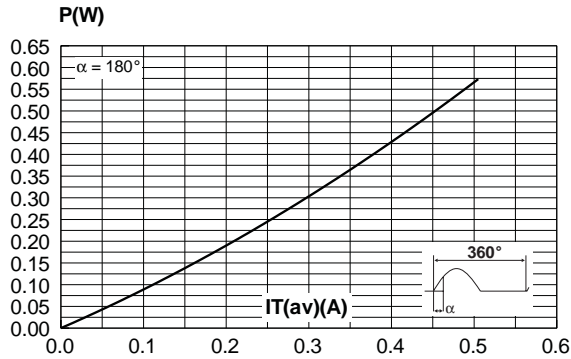


Fig. 2-1: Average and D.C. on-state current versus lead temperature.

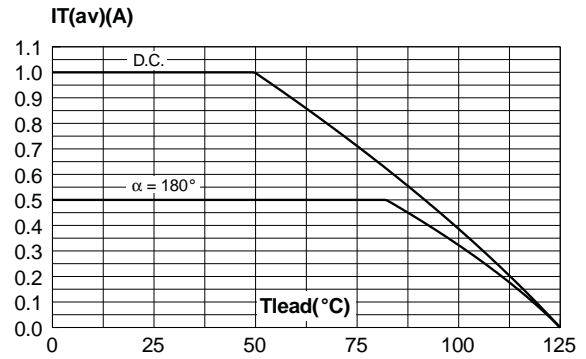


Fig. 2-2: Average and D.C. on-state current versus ambient temperature (device mounted on FR4 with recommended pad layout).

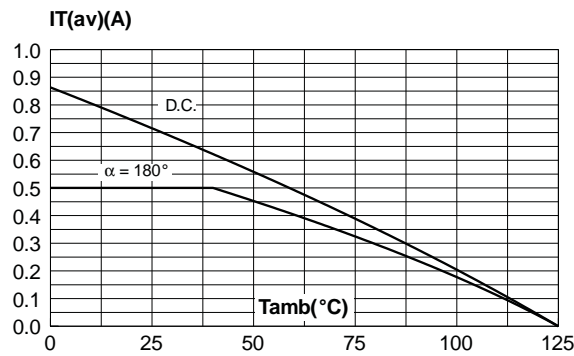


Fig. 3: Relative variation of thermal impedance junction to ambient versus pulse duration.

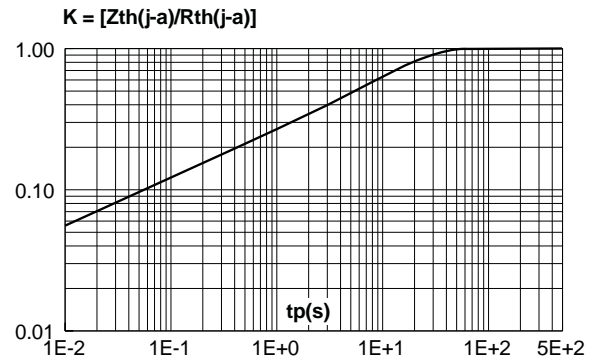


Fig. 4: Relative variation of gate trigger current, holding current and latching current versus junction temperature.

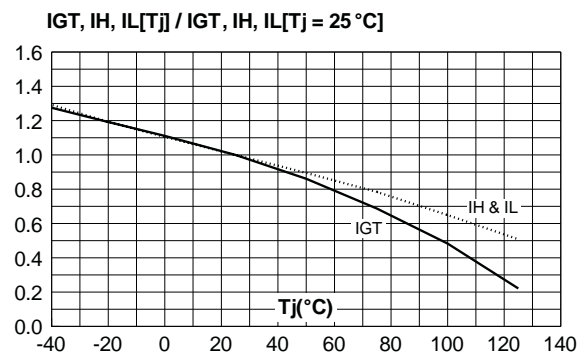


Fig. 5: Relative variation of holding current versus gate-cathode resistance (typical values).

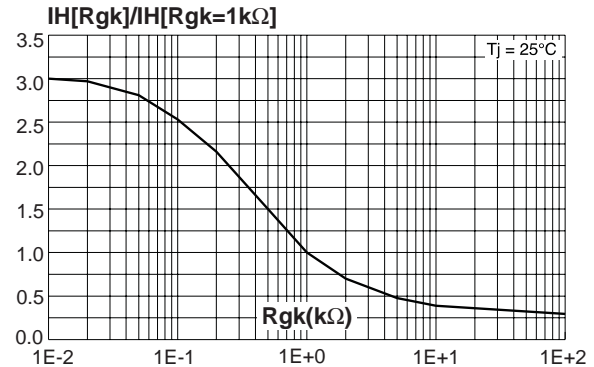


Fig. 6: Relative variation of dV/dt immunity versus gate-cathode resistance (typical values).

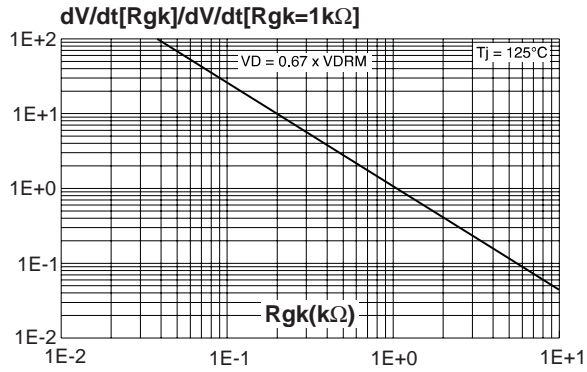


Fig. 8: Surge peak on-state current versus number of cycles.

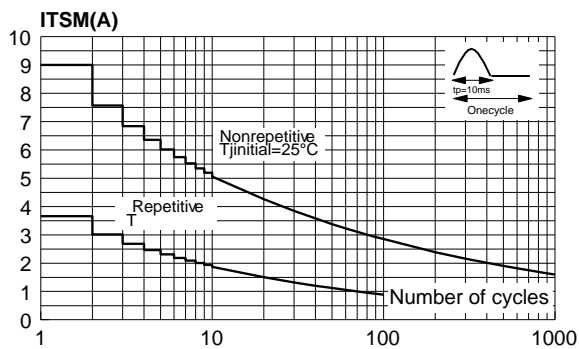


Fig. 10: On-state characteristics (maximum values).

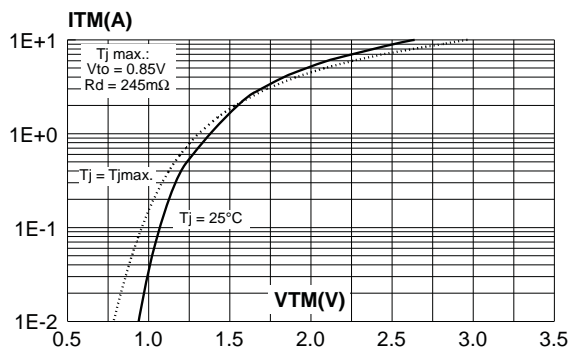


Fig. 7: Relative variation of dV/dt immunity versus gate-cathode capacitance (typical values).

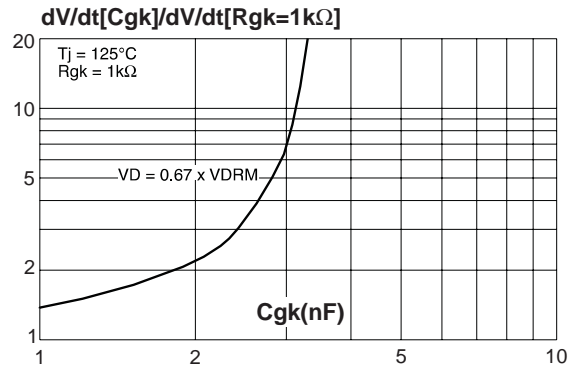
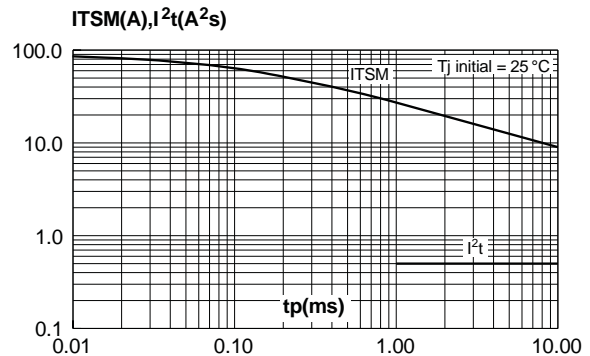
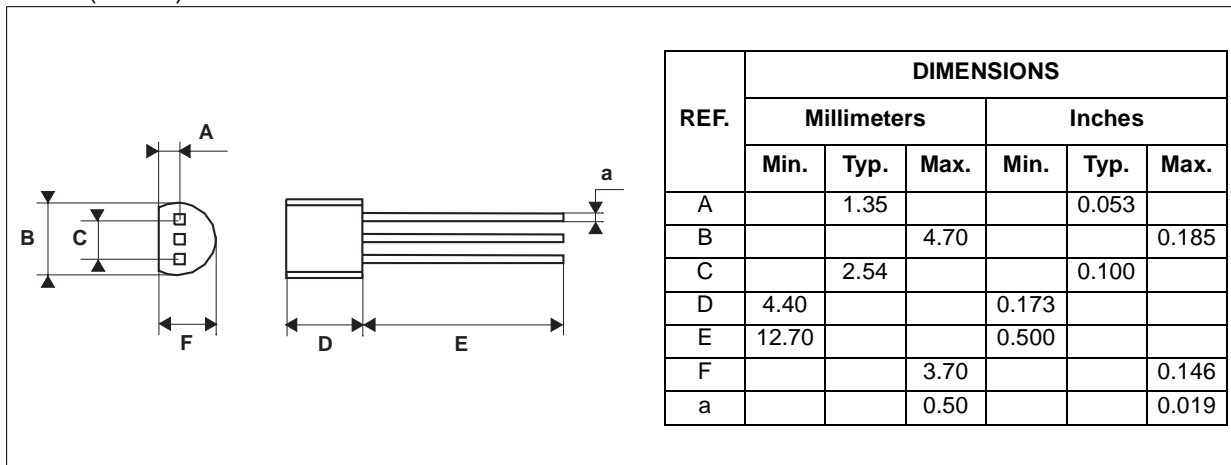


Fig. 9: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $tp < 10$ ms, and corresponding value of I^2t .



PACKAGE MECHANICAL DATA

TO-92 (Plastic)



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